	RANSMISSION BY FACSI	MILE (37 CFR 1.8)	Docket No. EN9-98-122US3
Applicant(s): Farquhar, et	al.		
Application No.	Filing Date	Examiner	Group Art Unit
09/781,730	02-12-2001	Goff II, John L.	1733
037781,750			
nvention:			
EMICONDUCTOR DEVIC	CE HAVING A THERMOSET-C	ONTAINING DIELECTRIC	MATERIAL AND METHODS
OR FABRICATING THE S		•	
			PROBIVED CENTRAL FAX CENTER
			AUG 1 6 2005
the archer positive that this	Respor	se to Interview Summary (1 pa	oge)
(Identify type of correspondence)			
is being facsimile transmit	ted to the United States Patent	and Trademark Office (Fax. N	o. <u>(571) 273-8300</u>
on August 16, 2			
		Tina Holf	ord
		(Typed or Printed Name of Perso	on Signing Certificate)
		1,000	has al
		(Signature	)
	•		
	Note: Each paper must ha	ive its own certificate of mailing.	•
		•	
			•

△ AUG-16-05 TUE 03:49 PM

FAX NO.

AUG 1 6 2005 P. 02

**DOCKET NO.: EN9-98-122US3** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Farquhar et al.

Examiner: Goff II, John L.

Serial No.: 09/781,730.

Art Unit: 1733

Filed: 02/12/2001

Title: SEMICONDUCTOR DEVICE HAVING A THERMOSET-CONTAINING DIELECTRIC MATERIAL AND METHODS FOR FABRICATING THE SAME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## Response to Interview Summary

Sir:

In response to the Examiner's Interview Summary mailed July 25, 2005, for the interview held July 12, 2005, Applicants acknowledge that said Interview Summary accurately reflects the substance of the interview.

Date: 08/16/2005

Jack P. Friedman

Registration No. 44,688

Schmeiser, Olsen & Watts 3 Lear Jet Lane, Suite 201 Latham, New York 12110 (518) 220-1850